

T24_vg1.8_disk
11WNSDVG1.8
CLIC_G un-damped @ 11.424 GHz
measurements versus simulations

A. Grudiev

CERN

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Acknowledgements

CERN:

M. Gerbaux

R. Zennaro

A. Olyunin

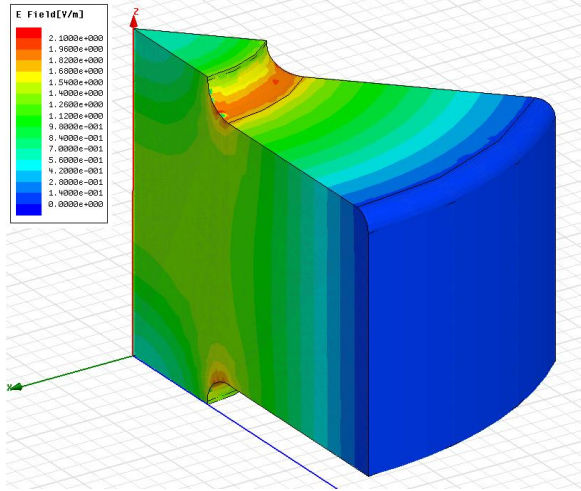
W. Wuensch

SLAC:

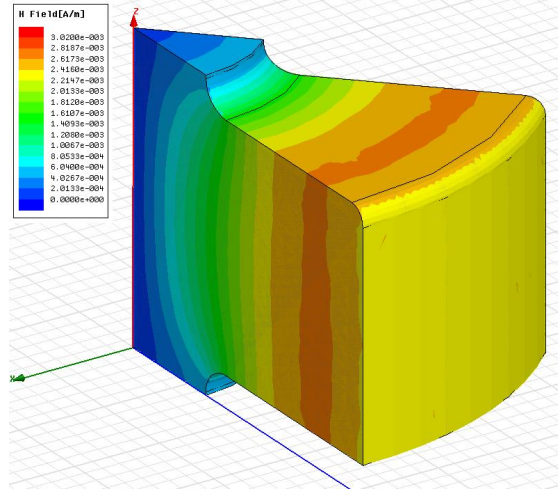
Z. Li

First cell

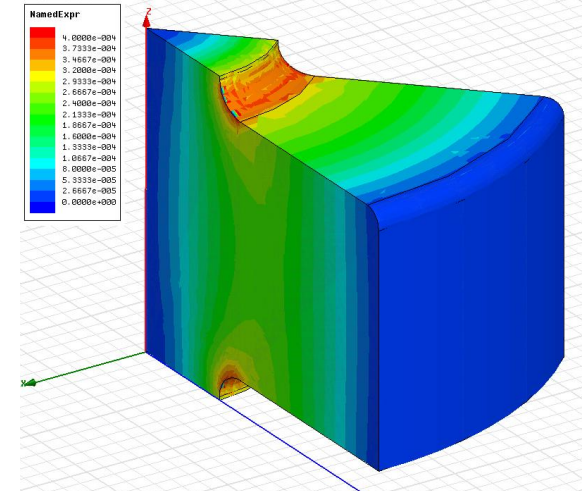
$$E_s/E_a$$



$$H_s/E_a$$

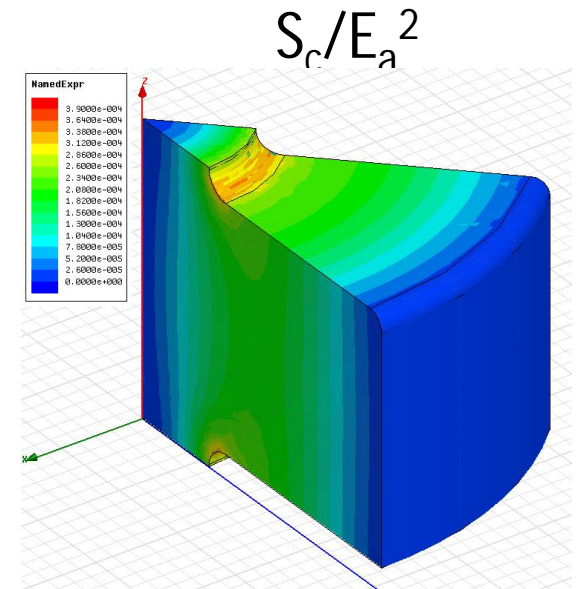
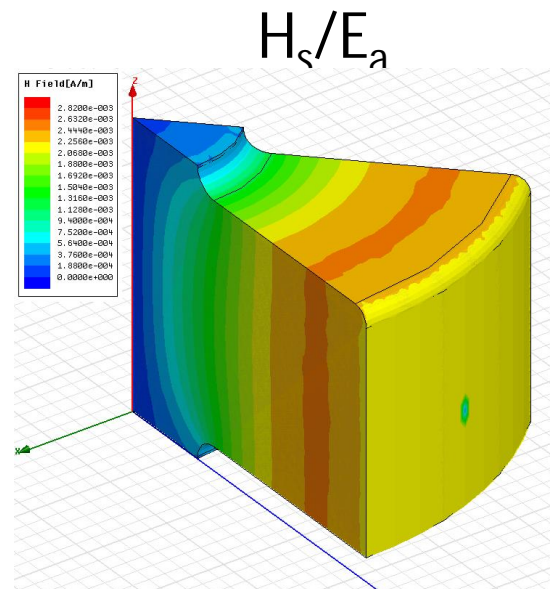
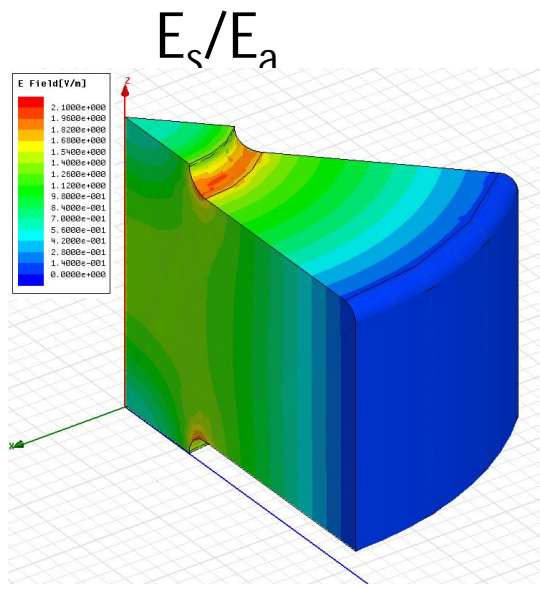


$$S_c/E_a^2$$



a [mm]	3.307
d [mm]	1.753
e	1.16
f [GHz]	11.433
Q(Cu)	6814
vg/c [%]	1.83
r'/Q [Linac Ω /m]	15198
E_s/E_a	1.95
H_s/E_a [mA/V]	2.6
S_c/E_a^2 [mA/V]	0.37

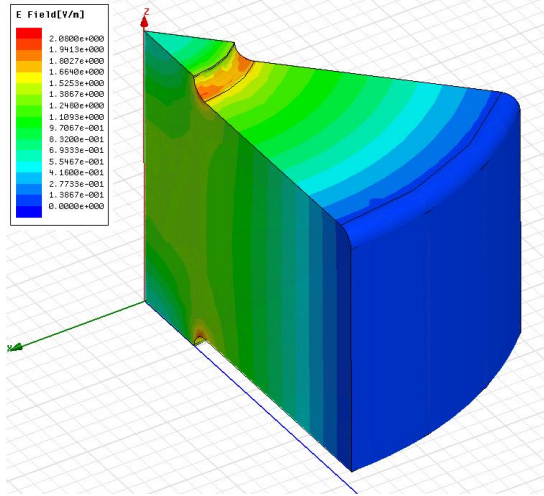
Middle cell



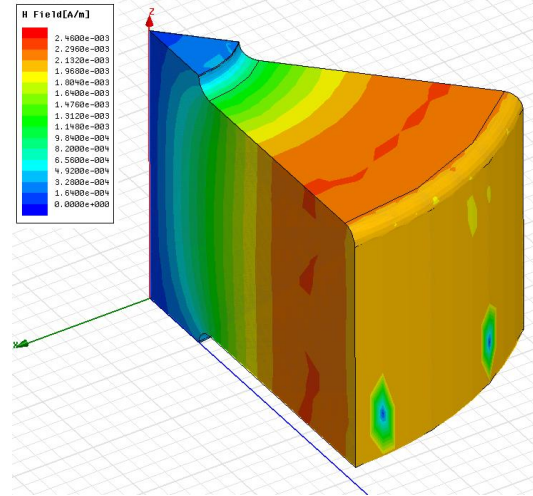
a [mm]	2.887
d [mm]	1.402
e	1.15
f [GHz]	11.432
Q(Cu)	6980
vg/c [%]	1.33
r'/Q [LinacΩ/m]	16960
Es/Ea	1.95
Hs/Ea [mA/V]	2.45
Sc/Ea ² [mA/V]	0.34

Last cell

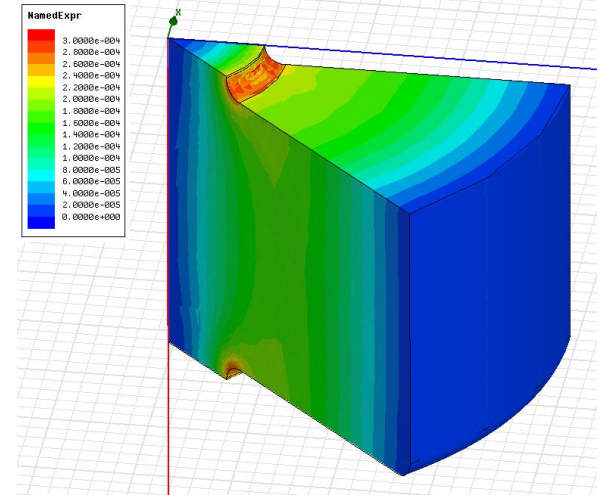
$$E_s/E_a$$



$$H_s/E_a$$



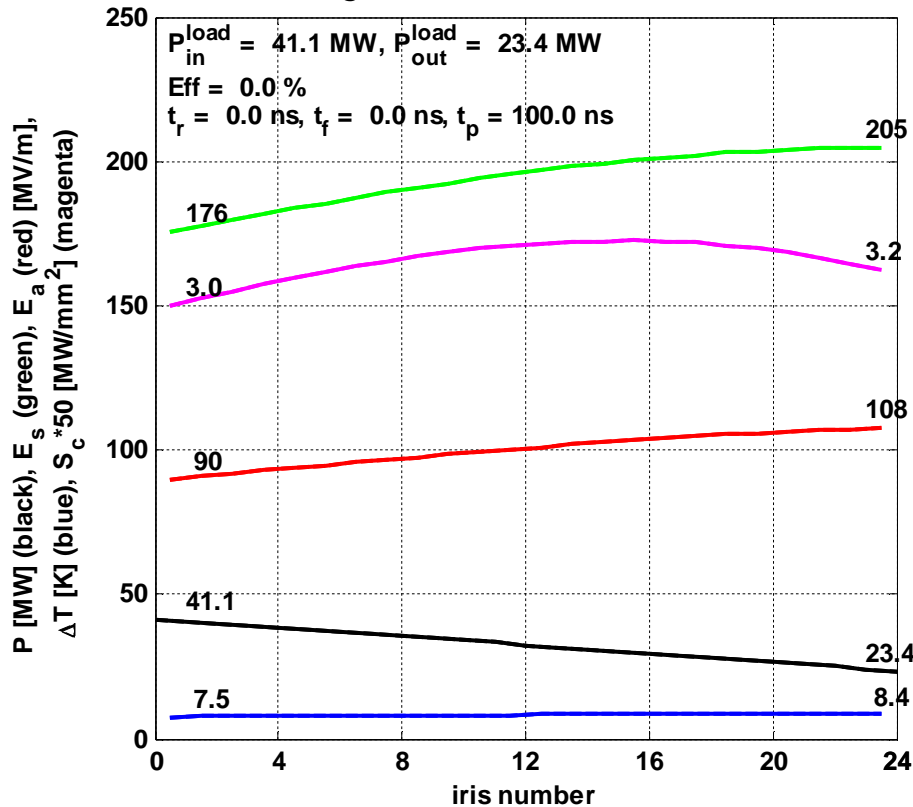
$$S_c/E_a^2$$



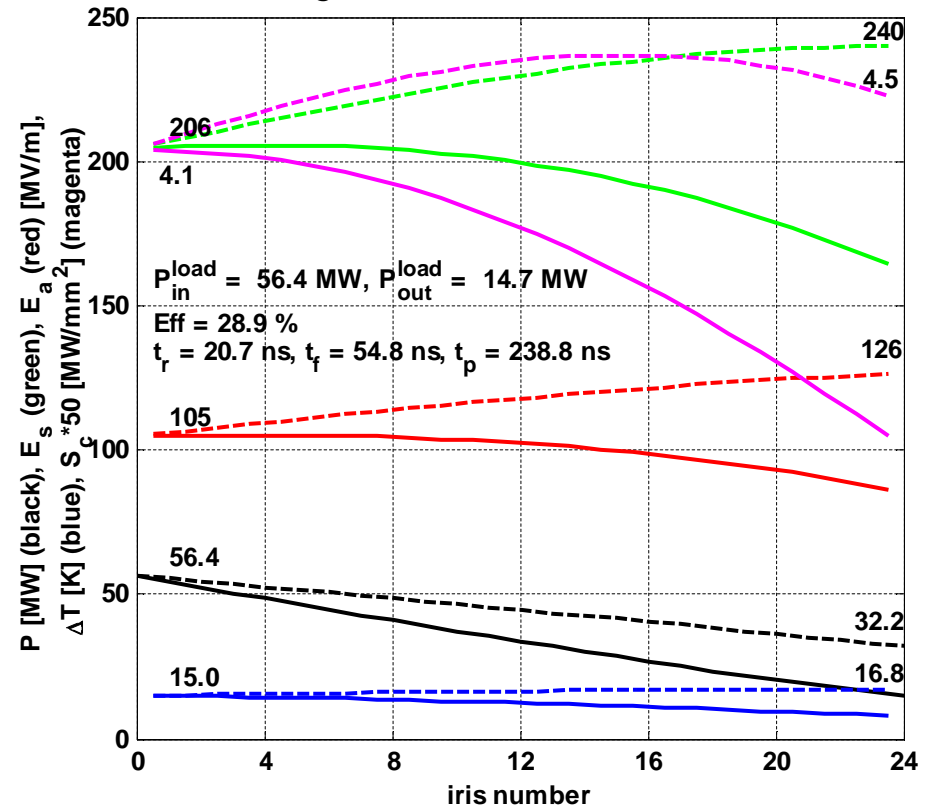
a [mm]	2.467
d [mm]	1.05
e	1.13
f [GHz]	11.426
Q(Cu)	7157
vg/c [%]	0.92
r'/Q [LinacΩ/m]	18713
Es/Ea	1.9
Hs/Ea [mA/V]	2.3
Sc/Ea ² [mA/V]	0.28

Gradient in 24 regular cells

Average unloaded of 100 MV/m



Average loaded of 100 MV/m



$$\frac{dP}{dz} = -\frac{\omega}{Qv_g} P - \sqrt{\frac{\omega R'}{v_g Q}} I P^{\frac{1}{2}}$$

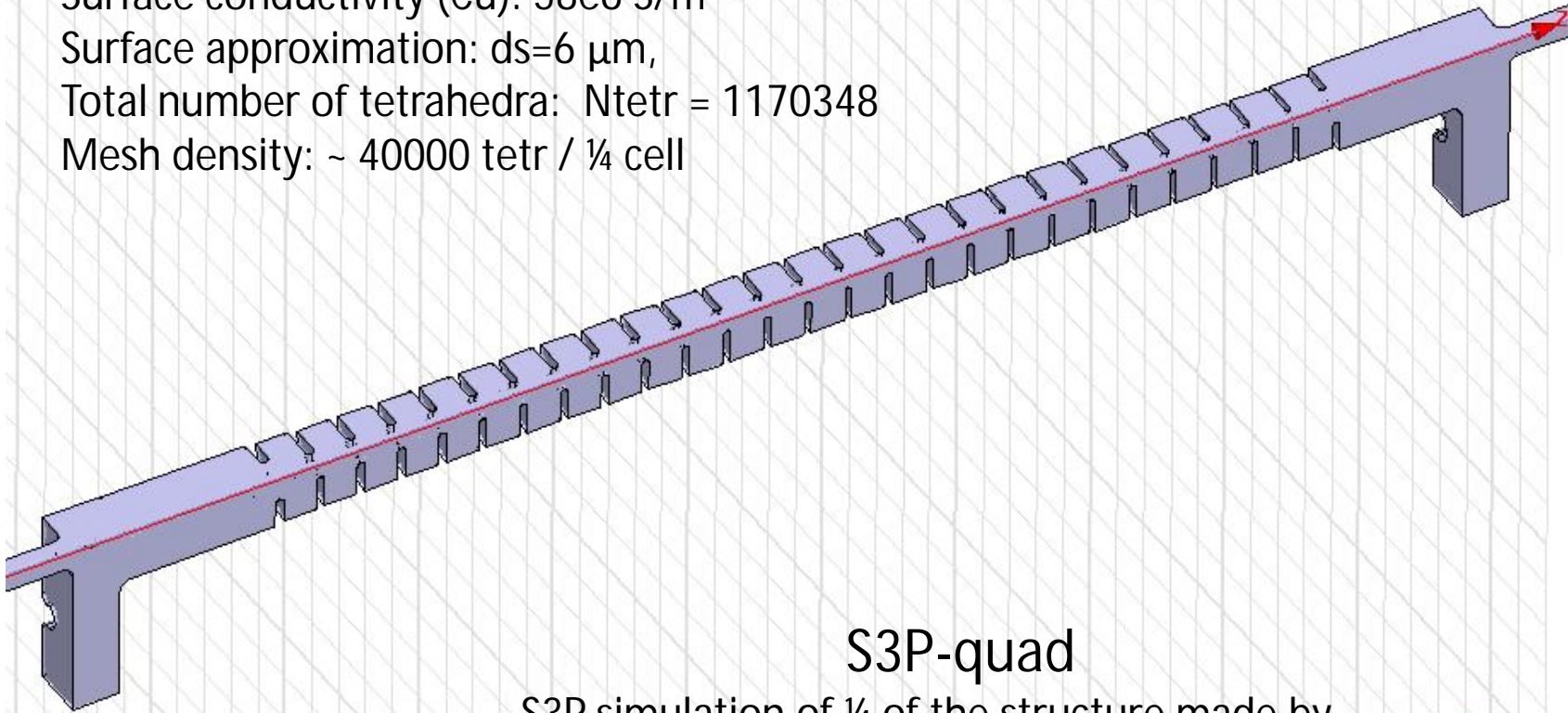
Number of regular cells: Nc	24
Bunch population: N	3.72×10^9
Number of bunches: Nb	312
Bunch separation: Ncycl	6 rf cycles

Simulation setup 1 & 2

HFSS-quad

HFSS simulation of $\frac{1}{4}$ of the structure:
Surface conductivity (Cu): $58e6$ S/m
Surface approximation: $ds=6$ μm ,
Total number of tetrahedra: $N_{\text{tetr}} = 1170348$
Mesh density: ~ 40000 tetr / $\frac{1}{4}$ cell

HFSS v10.1



S3P-quad

S3P simulation of $\frac{1}{4}$ of the structure made by
Zenghai Li at SLAC-ACD
Surface conductivity (Cu): $57e6$ S/m different



Simulation setup 3

HFSS-cells + couplers

HFSS simulation of $\frac{1}{4}$ of input coupler + segment of 5 deg. of the cells + $\frac{1}{4}$ of output coupler :

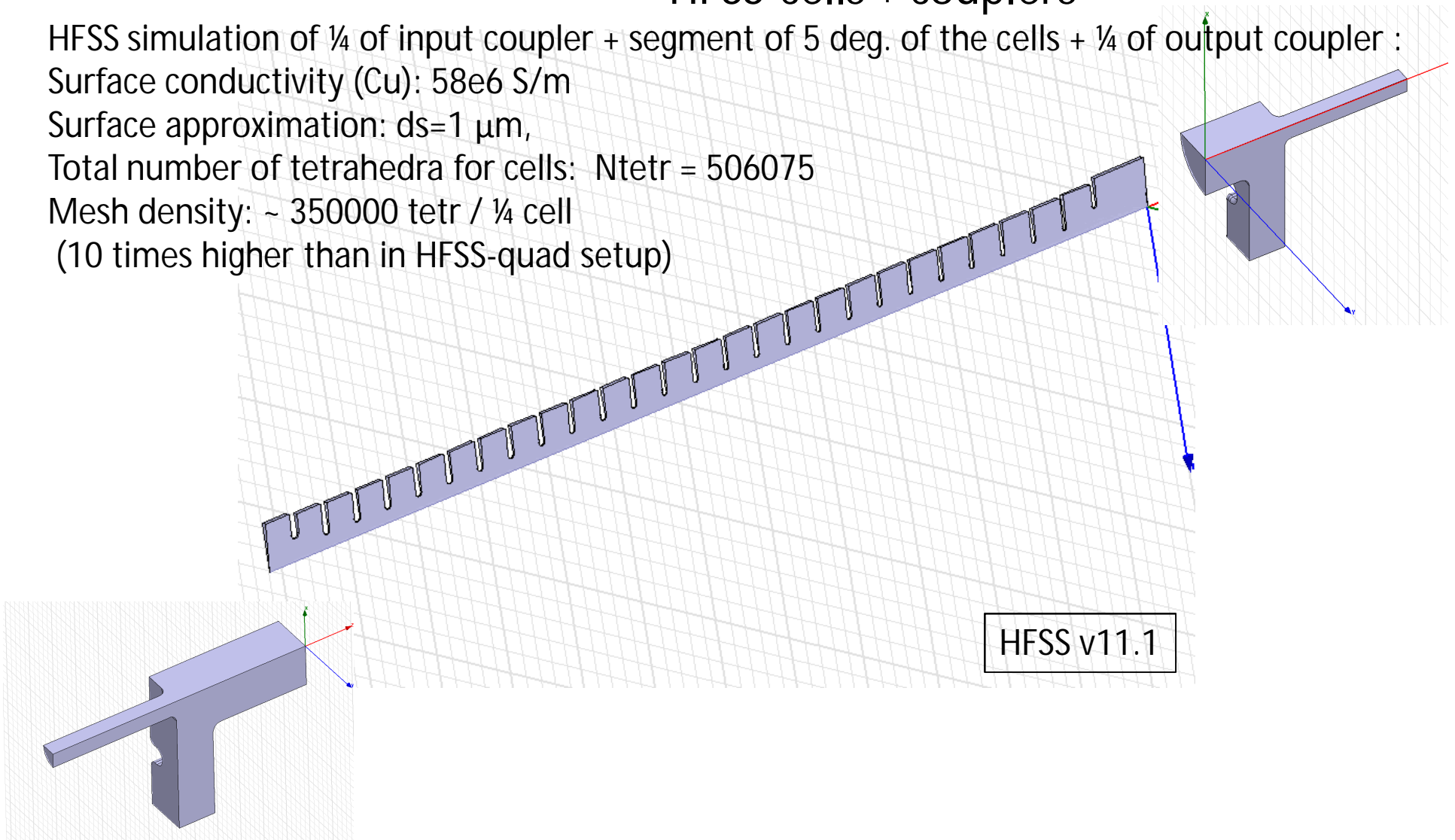
Surface conductivity (Cu): $58e6$ S/m

Surface approximation: $ds=1$ μm ,

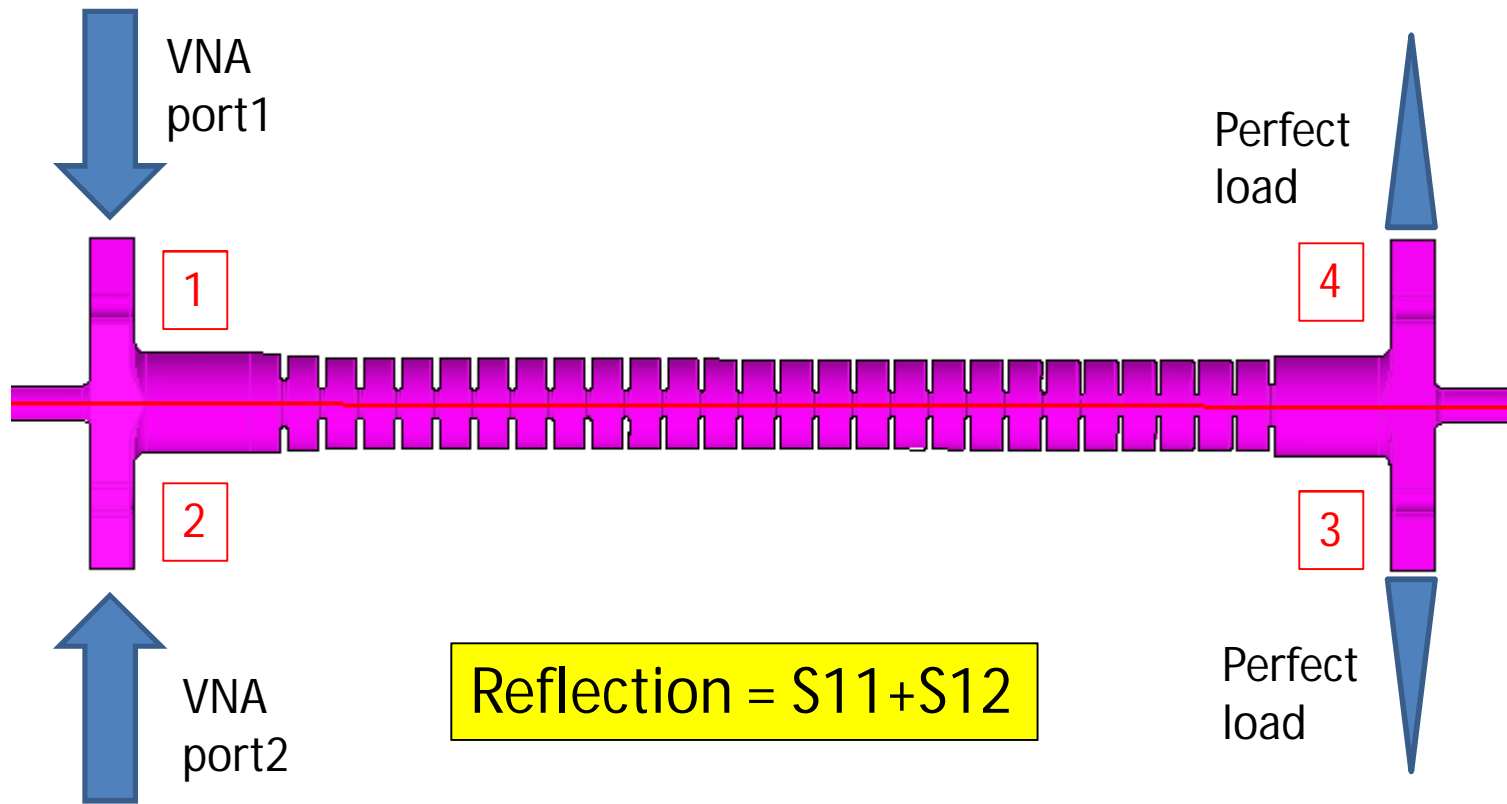
Total number of tetrahedra for cells: $N_{\text{tetr}} = 506075$

Mesh density: ~ 350000 tetr / $\frac{1}{4}$ cell

(10 times higher than in HFSS-quad setup)



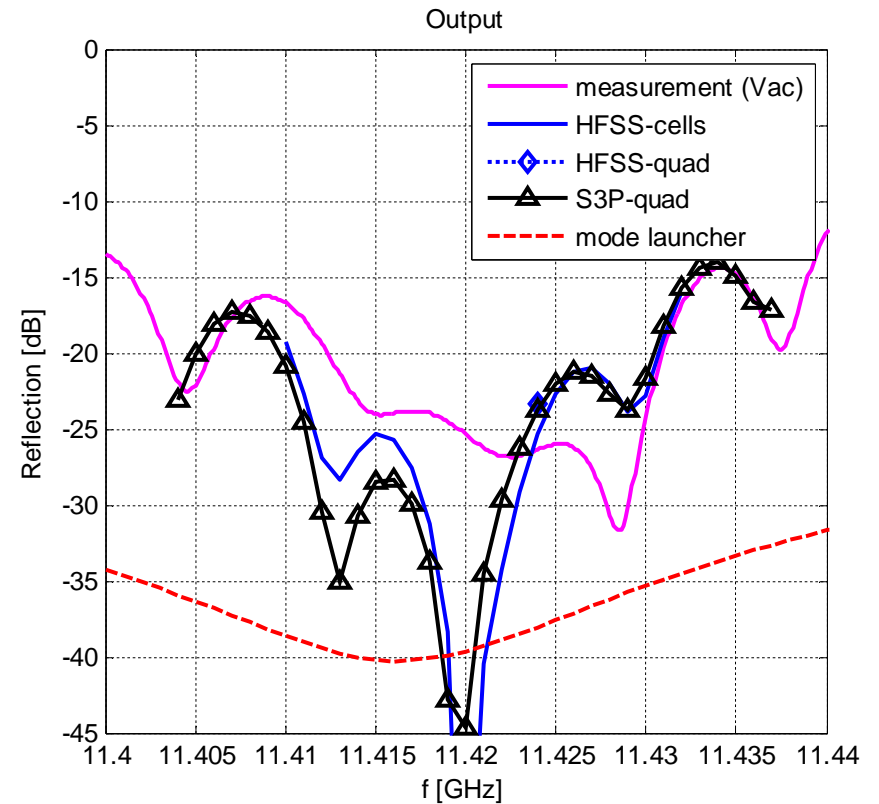
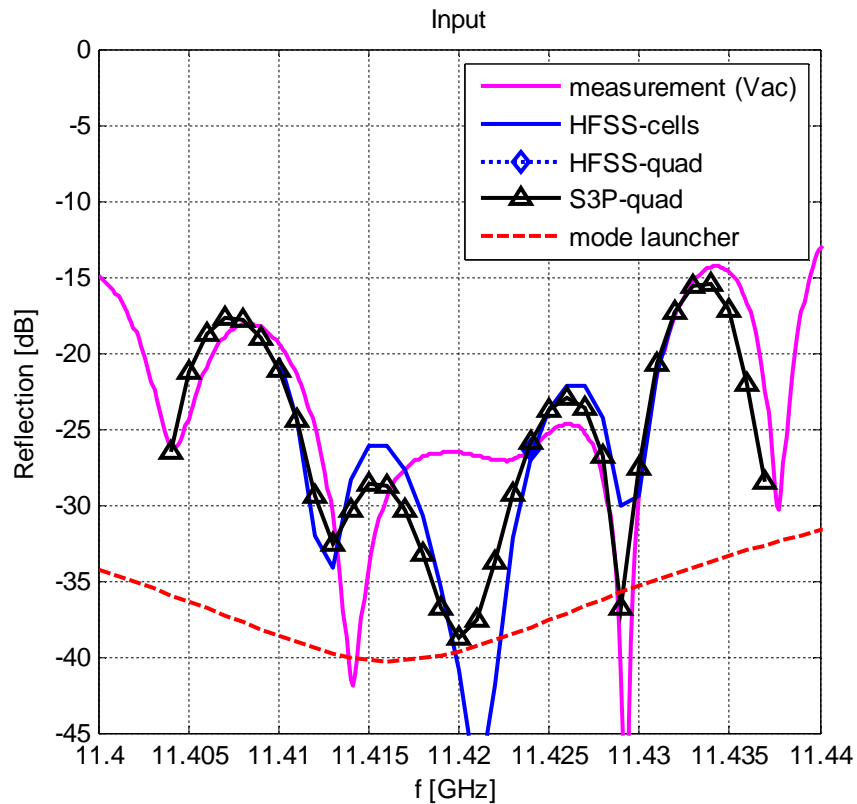
Measurement setup 1 (reflections)



Frequency correction due to air ($\epsilon = 1.00059$)

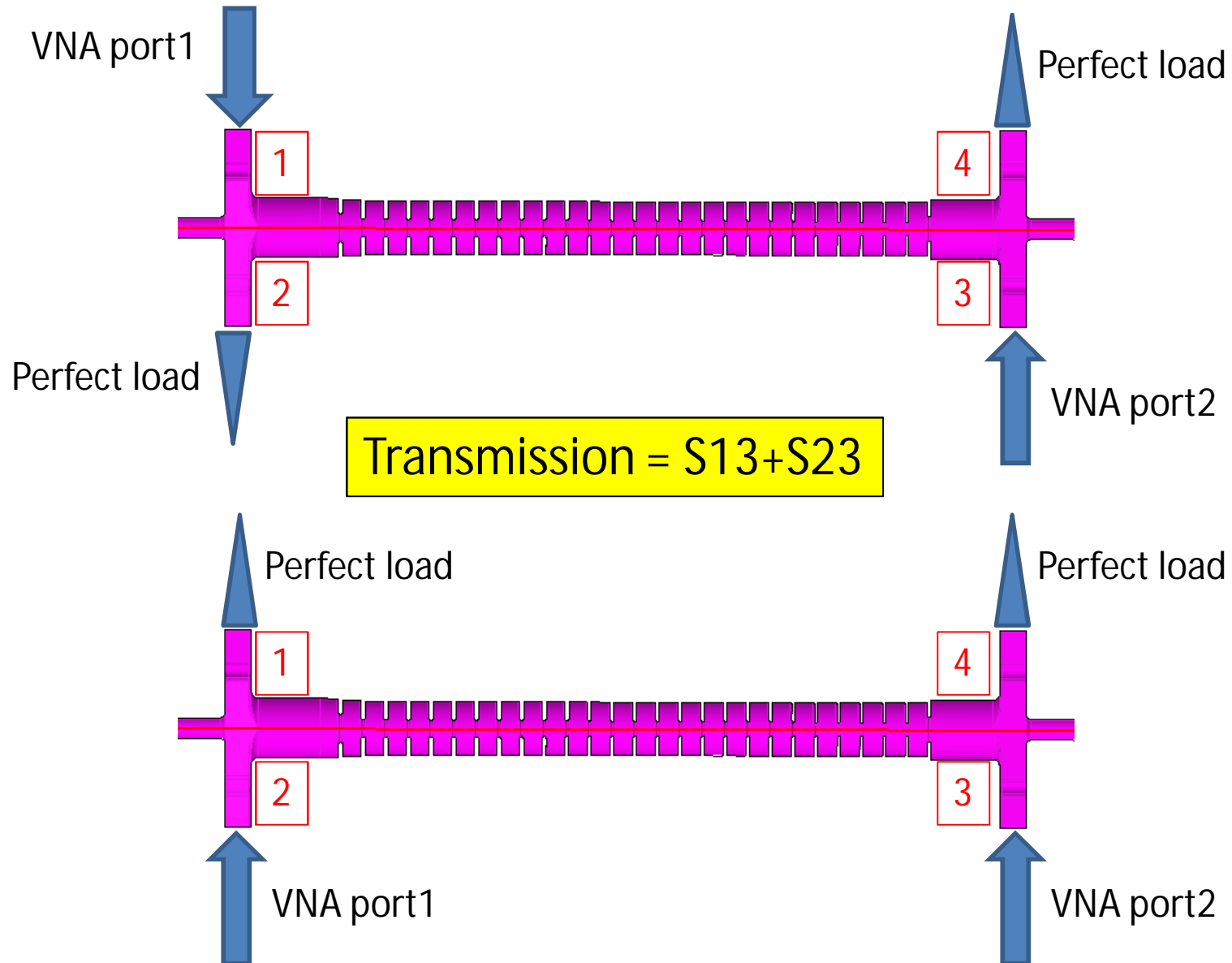
Frequency in vacuum: $f' = f \cdot \sqrt{1.00059} \approx f + 3.5 \text{ MHz @ X-band}$

Reflection: comparison

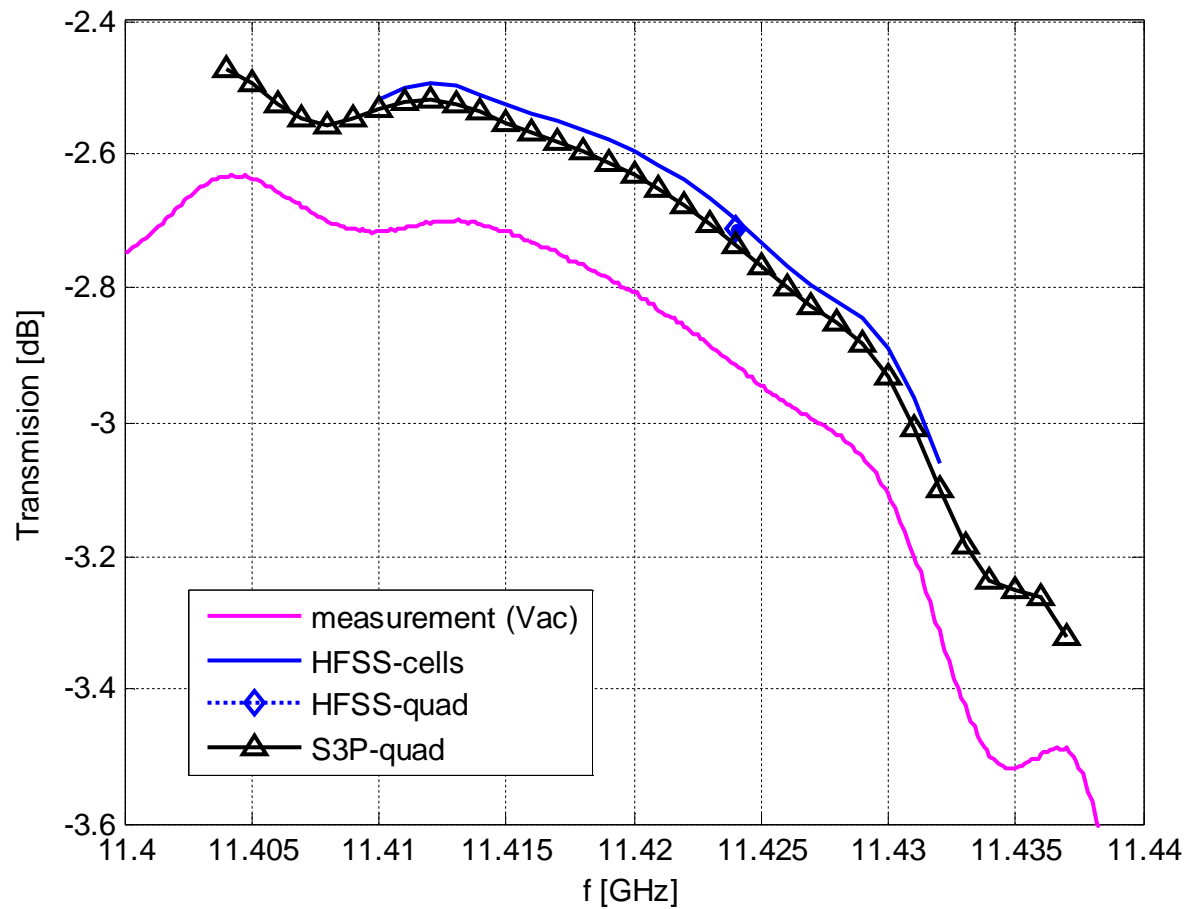


There is very small (~ 1 MHz) or no difference in frequency between simulations and the air corrected measurements

Measurement setup 2 (transmission)



Transmission: comparison



- There is small difference between HFSS and S3P simulation results due to different conductivity used in the simulations
- Both simulation results show higher transmission than air corrected measurements by about 0.2 dB

Some useful equations

$$P_{out} = P_{in} e^{-2\tau} \text{ where } \tau = \ln|S_{12}| \text{ attenuation}$$

On the other hand

$$P_{out} = P_{in} e^{-\frac{\omega t_f}{Q}} \text{ where } Q = \frac{\omega W}{P_{loss}} \text{ - average quality factor}$$

$$t_f = \frac{W_0}{P_{in}} \equiv \frac{d(\phi = \arg S_{12})}{d\omega} \text{ - filling time } \equiv \text{group delay}$$

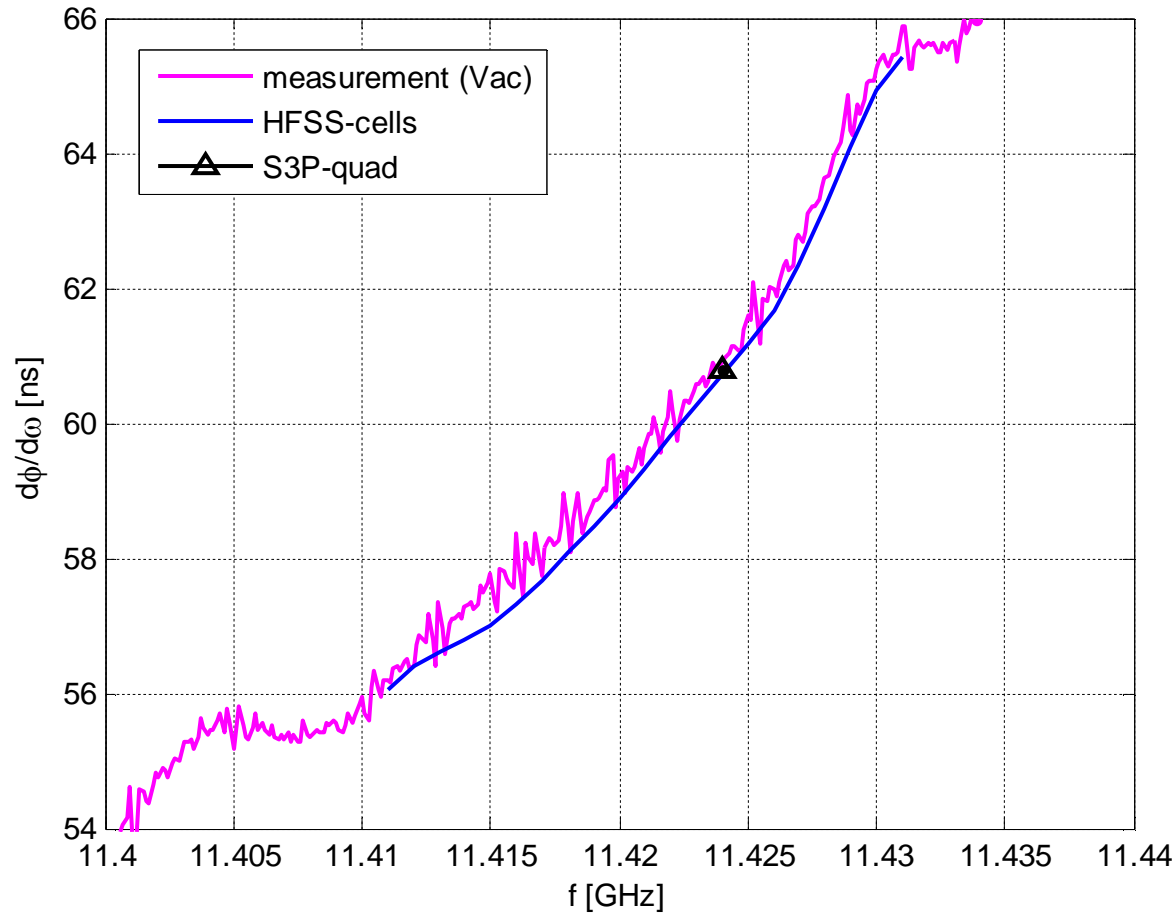
W - stored energy in lossy structure

W_0 - stored energy in lossfree structure

Finally

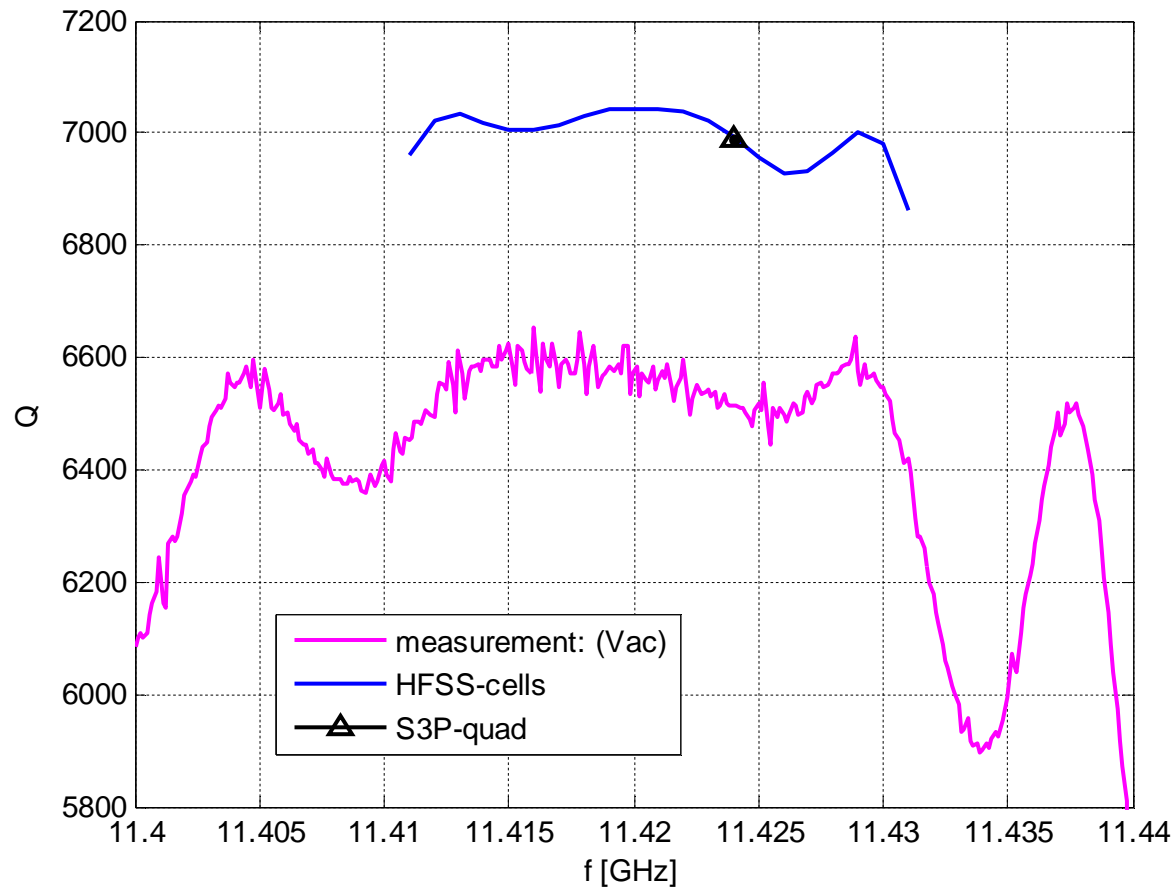
$$Q = \frac{\omega t_f}{2\tau}$$

Transmission: comparing group delay



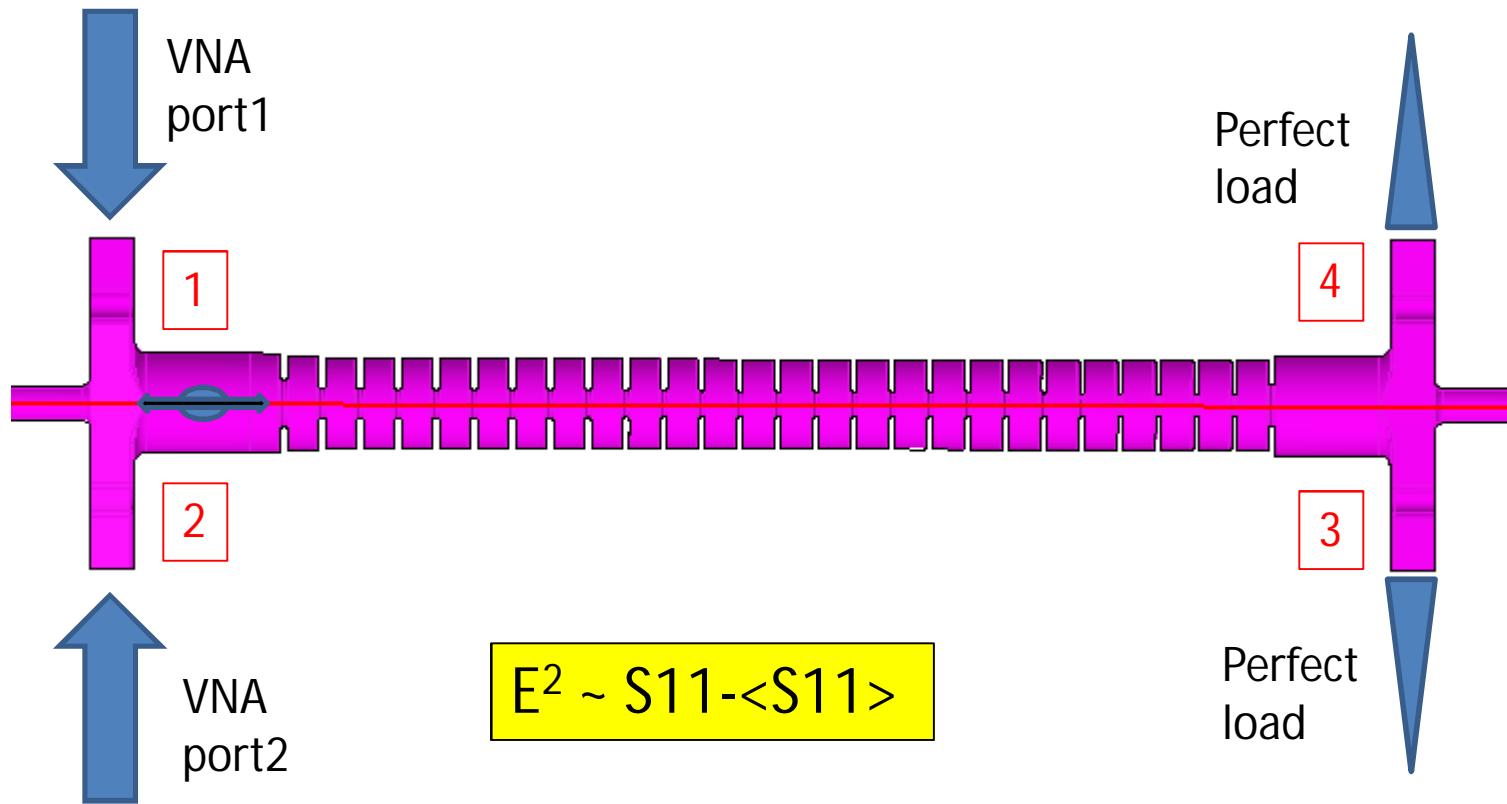
There is no difference between both HFSS and S3P simulations and the air corrected measurements

Transmission: comparing Q-factor



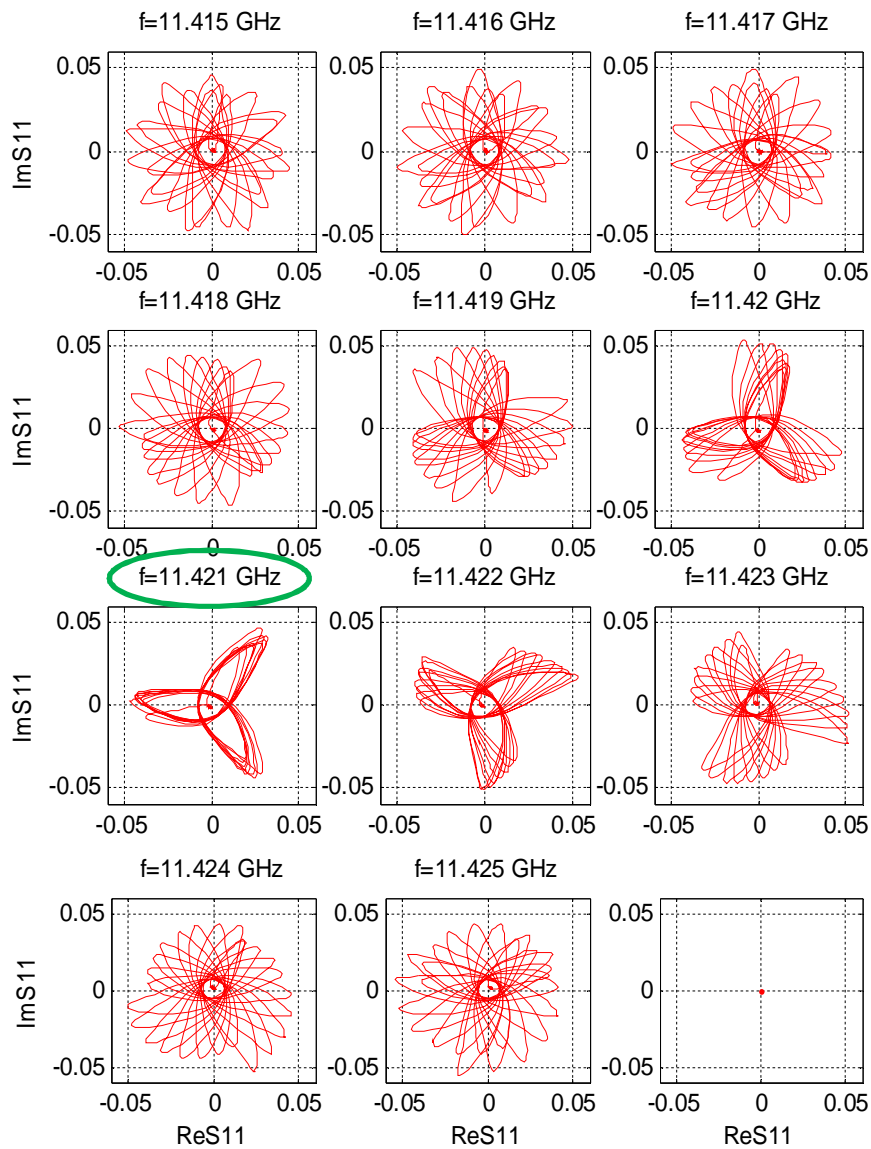
- There is no difference in Q-factor (~7000) between HFSS and S3P simulations.
- The measured Q-factor of about 6600 is lower than the simulated value by about 6 %.

Measurement setup 3 (bead pull)

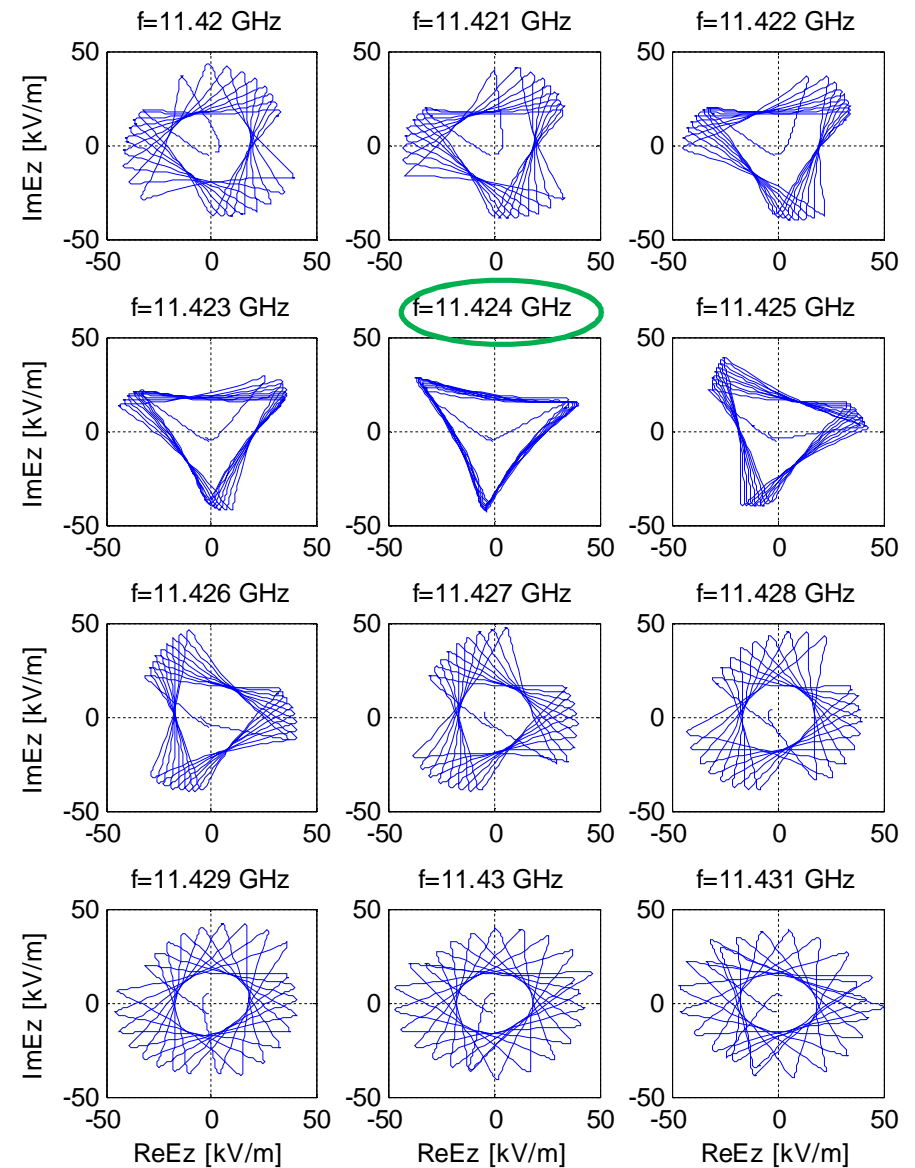


Bead pull in complex plane

Measurements: S_{11} - $\langle S_{11} \rangle$



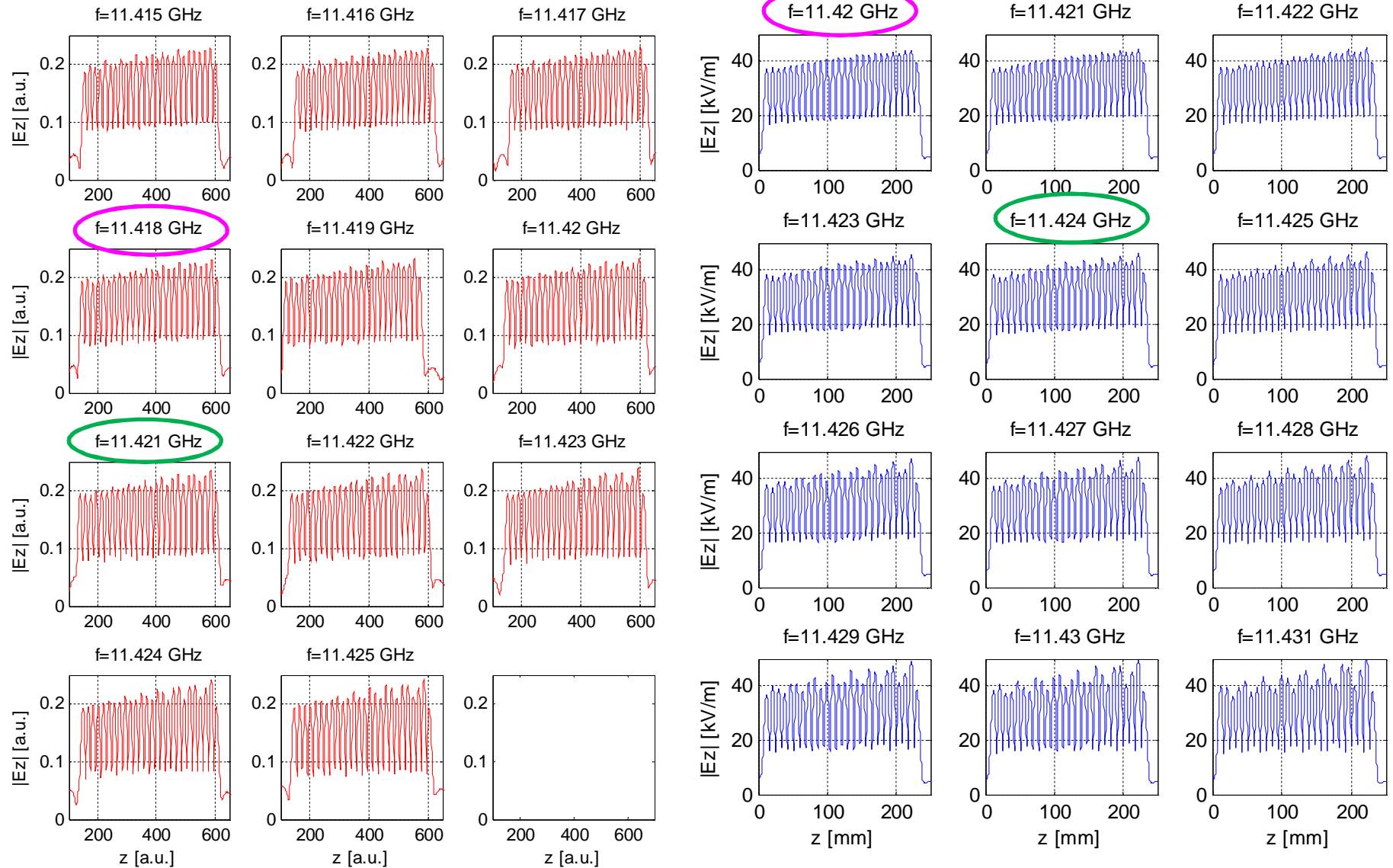
HFSS-cells: E



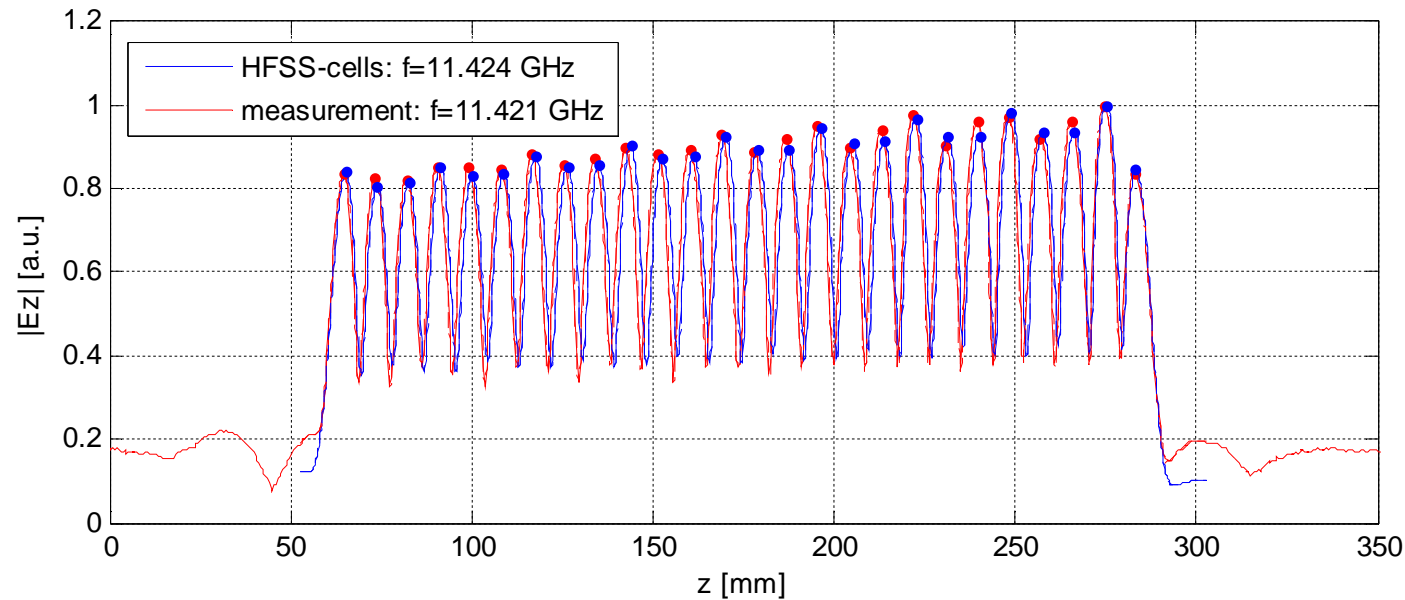
Bead pull: field magnitude

Measurements: $|\sqrt{S11-\langle S11 \rangle}|$

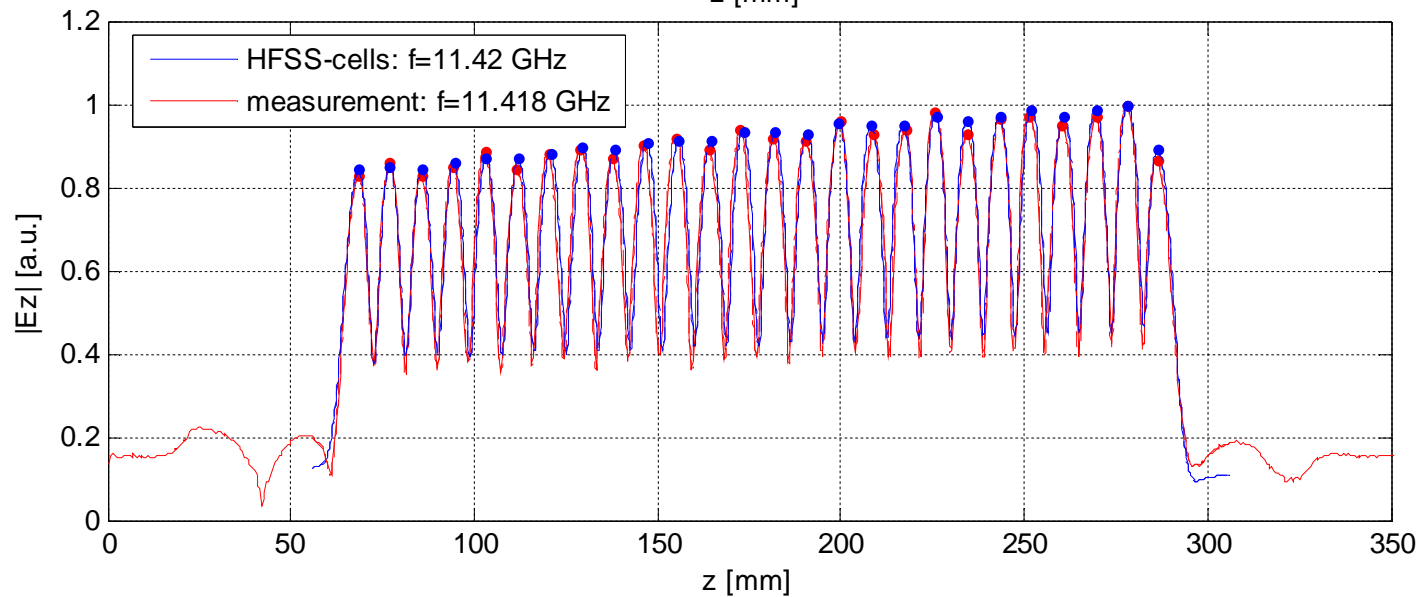
HFSS-cells: $|E|$



Field distribution at different frequencies

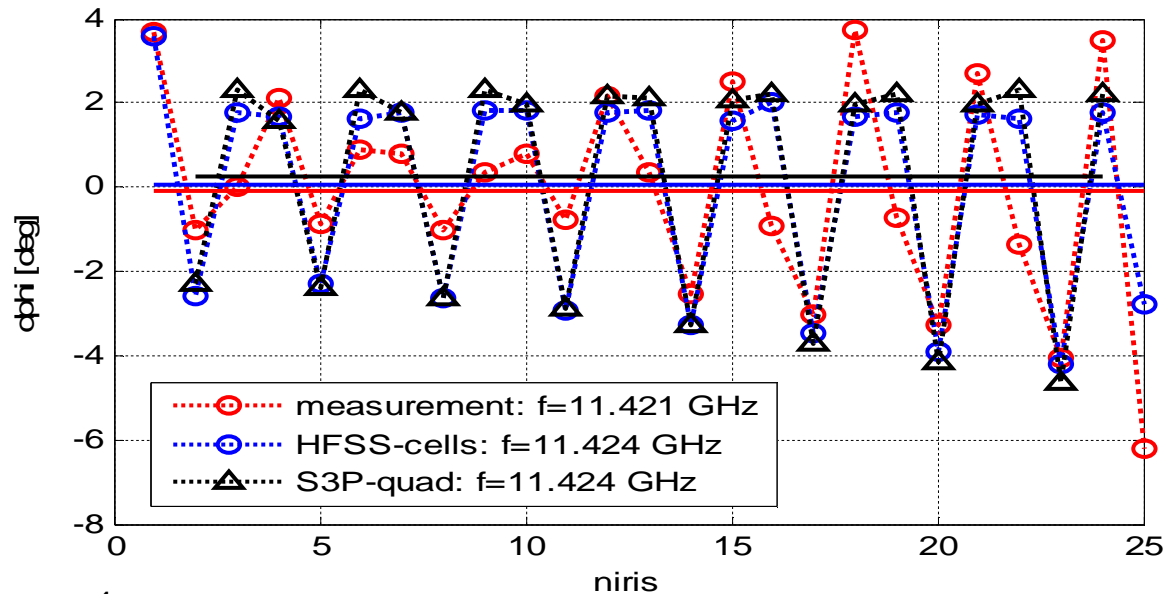


120° rf phase advance per cell frequency
11.424 GHz

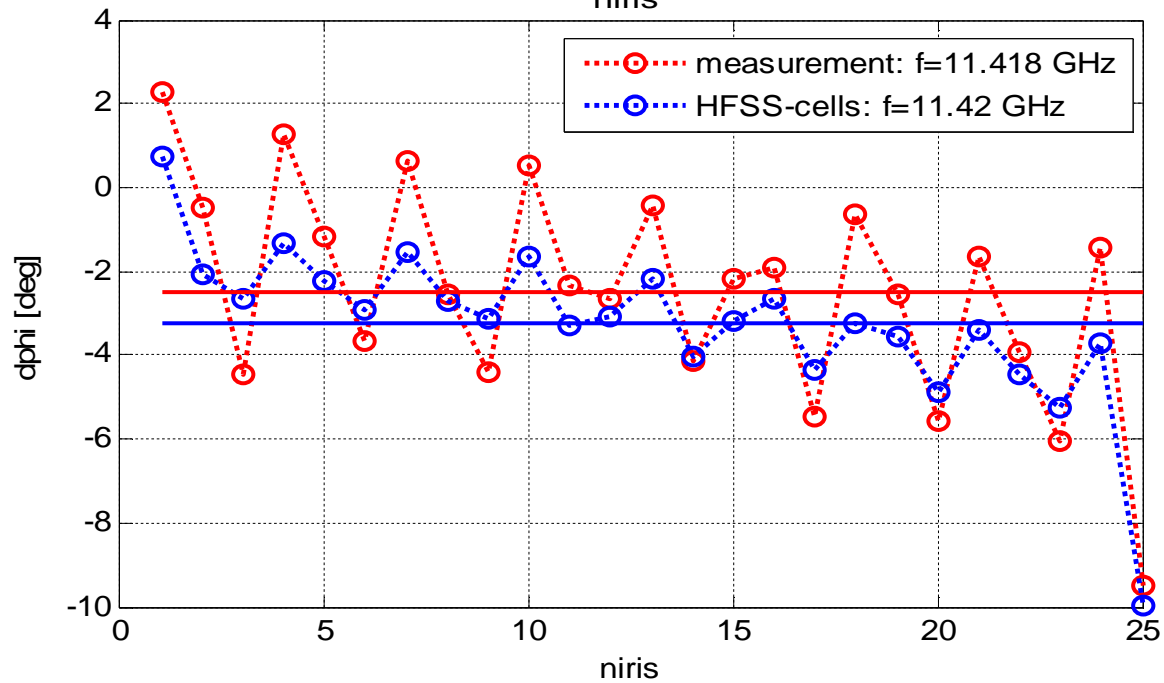


Best match frequency
11.420 GHz

RF phase advance per cell at different frequencies



120° rf phase advance per cell frequency: 11.424 GHz



Best match frequency: 11.420 GHz

Summary table for T24_vg1.8_disk

	S12	Pout/ Pin	$\tau=0.5\ln$ (Pout/ Pin)	tf=d ϕ / d ω [ns]	tf=W0 /Pin [ns]	Q= ω tf/2 τ	Q= ω W /(Pin- Pout)	Q= ω W /Ploss	Pin100 24 cells [MW]
Measurements (Vac)	0.715	0.511	0.336	60.9	-	6600	-	-	
HFSS ¼	0.732	0.536	0.312	-	58.4	6720	7010	7010	
HFSS	0.731	0.534	0.313	60.7	59.8	6960	6940	6640	
InCoup	0.99875	0.9975	0.0013	<-	0.46	12700	13000	13200	
OutCoup	0.99889	0.9978	0.0011	<-	0.36	11800	12300	12300	
Cells 24+2	0.733	0.537	0.311	59.9	59.0	6910	6880	6580	42.2
3-cells model		0.569- 0.533	0.282- 0.315	-	54.8- 59.37	6974- 6764	6980		41.1
S3P (SLAC)	0.730	0.533	0.315	60.8		6927($\sigma=57e6$) 6988($\sigma=58e6$)			42.4

Summary on comparison

- Simulation results of HFSS and S3P show very good agreement
- Q-factor
 - All 3 different ways of calculating Q-factor: S3P, HFSS-S-parameter solver and HFSS-eigenmode solver give very close values of about 7000
 - The measurements of the T24_vg1.8_disk structure made at CERN show 6 % lower Q-factor of 6600
- RF phase advance
 - Both HFSS and S3P simulations and air corrected measurements simulations show 120° rf phase advance frequency of 11.424 GHz which is the design frequency
 - Good agreement (± 0.5 MHz) between simulations and measurements demonstrates extremely high (sub-micron) precision of machining. For example, it is equivalent to ± 0.6 μm tolerance on the outer wall radius RF phase advance
- Structure matching
 - There is a design error in structure matching of about 4 MHz. The match frequency is 11.420 GHz . To some extent this is also in agreement with the measurements

HFSS S-par solver: v10.1 versus v11.1

Simulation setup 4

HFSS-cells + couplers

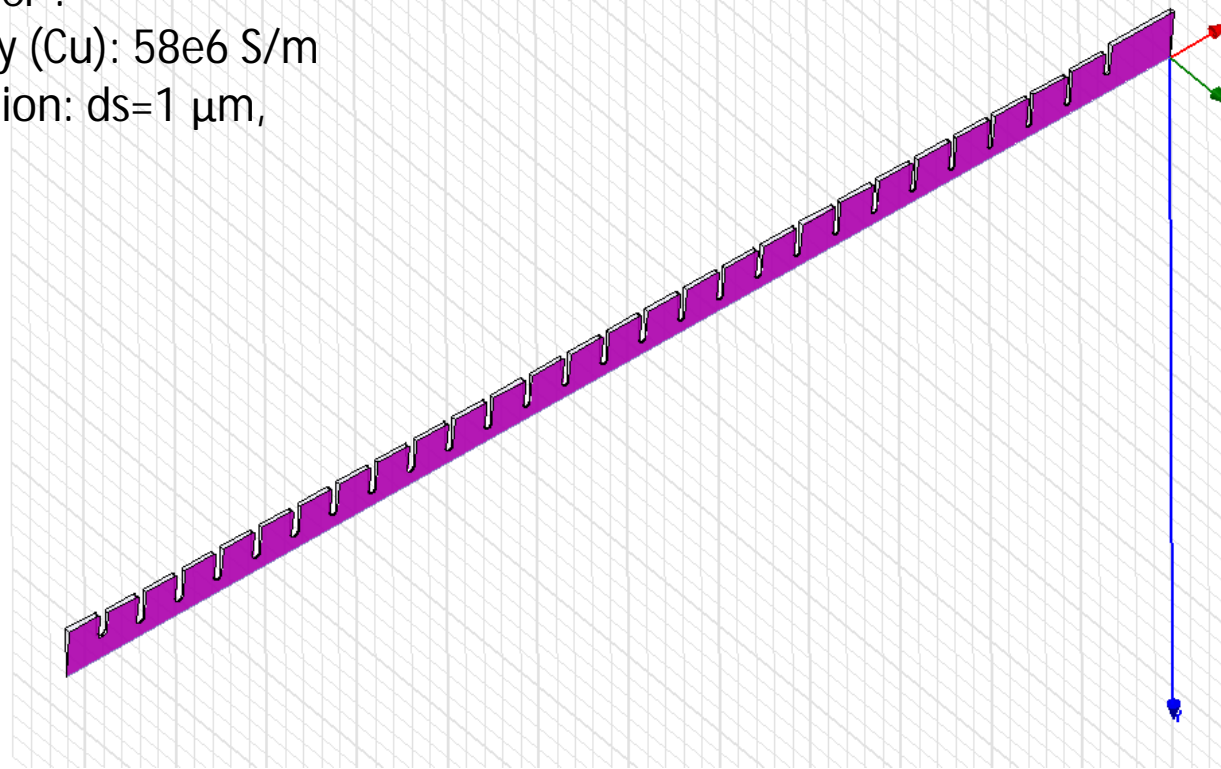
HFSS simulation of $\frac{1}{4}$ of input coupler

+ segment of the cells made in HFSS by 5 deg. Sweep (3D geometry created in HFSS)

+ $\frac{1}{4}$ of output coupler :

Surface conductivity (Cu): $58e6$ S/m

Surface approximation: $ds=1$ μm ,

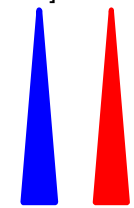
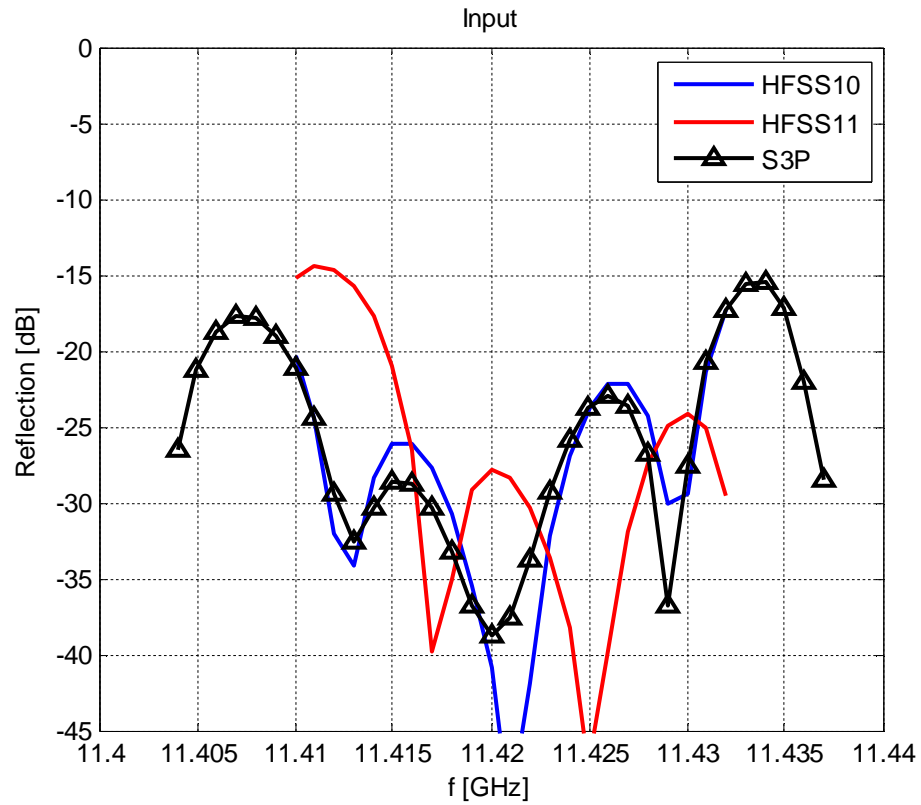


HFSS v11.1

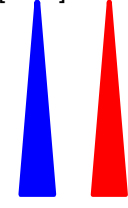
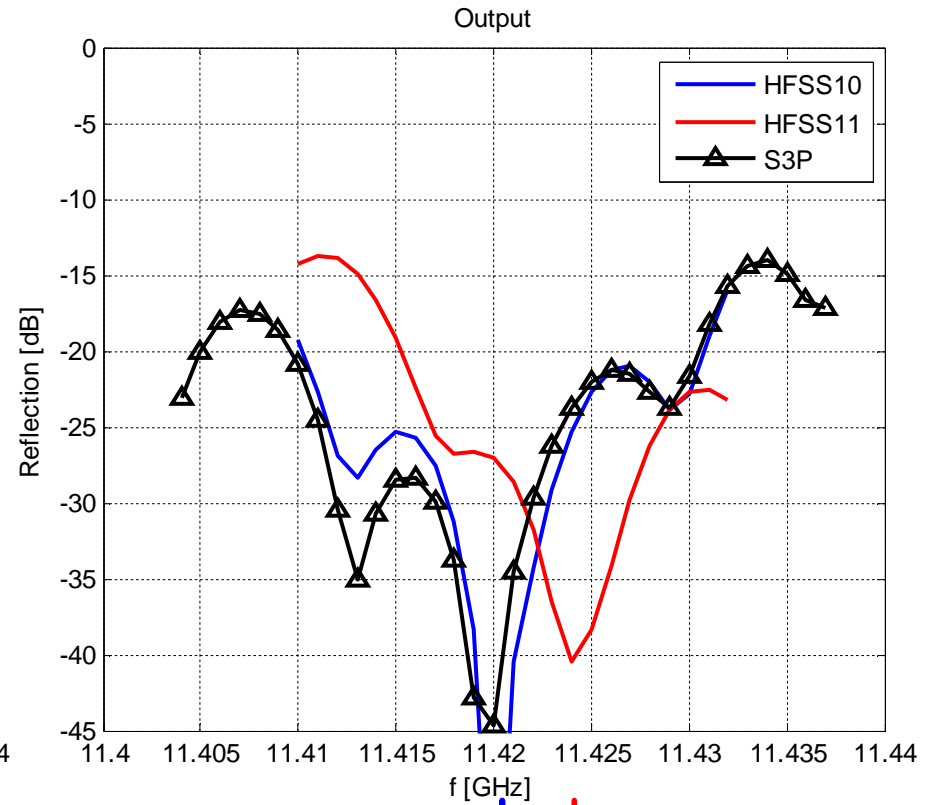
versus

HFSS v10.1

Reflection

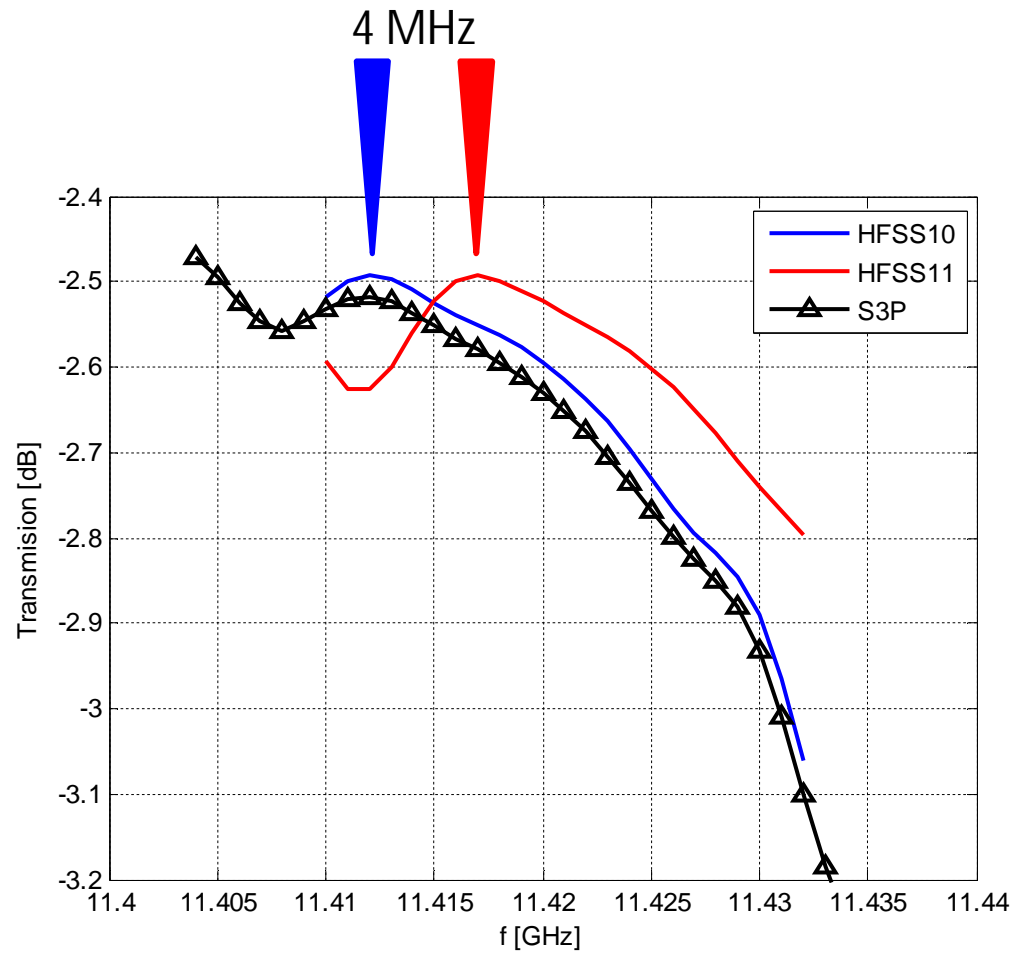


4 MHz

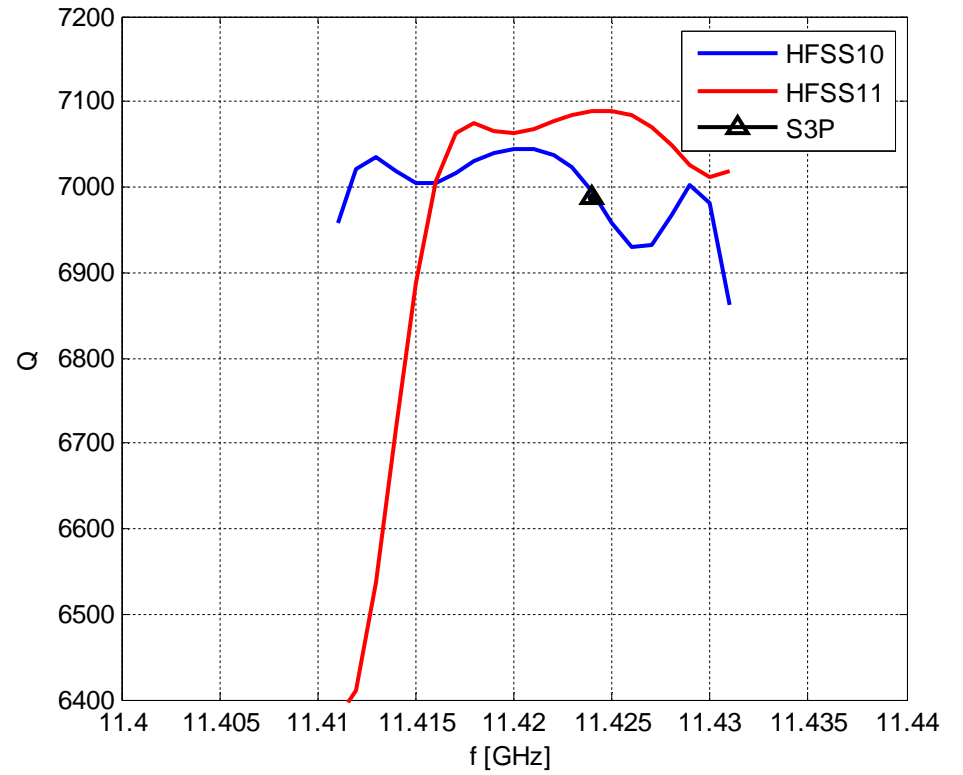
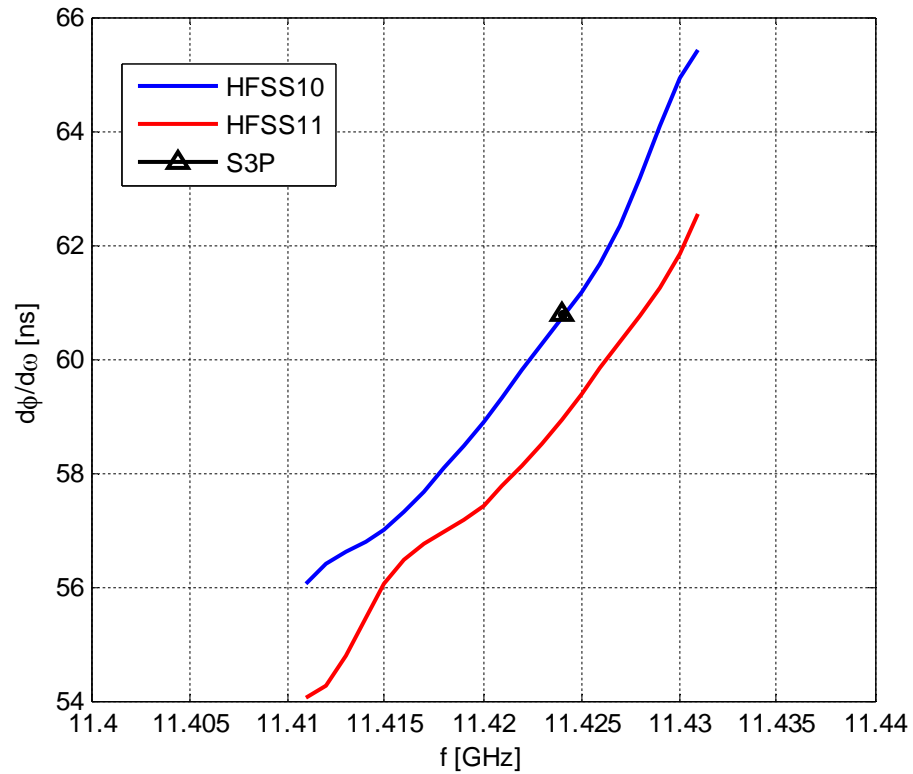


4 MHz

Transmission



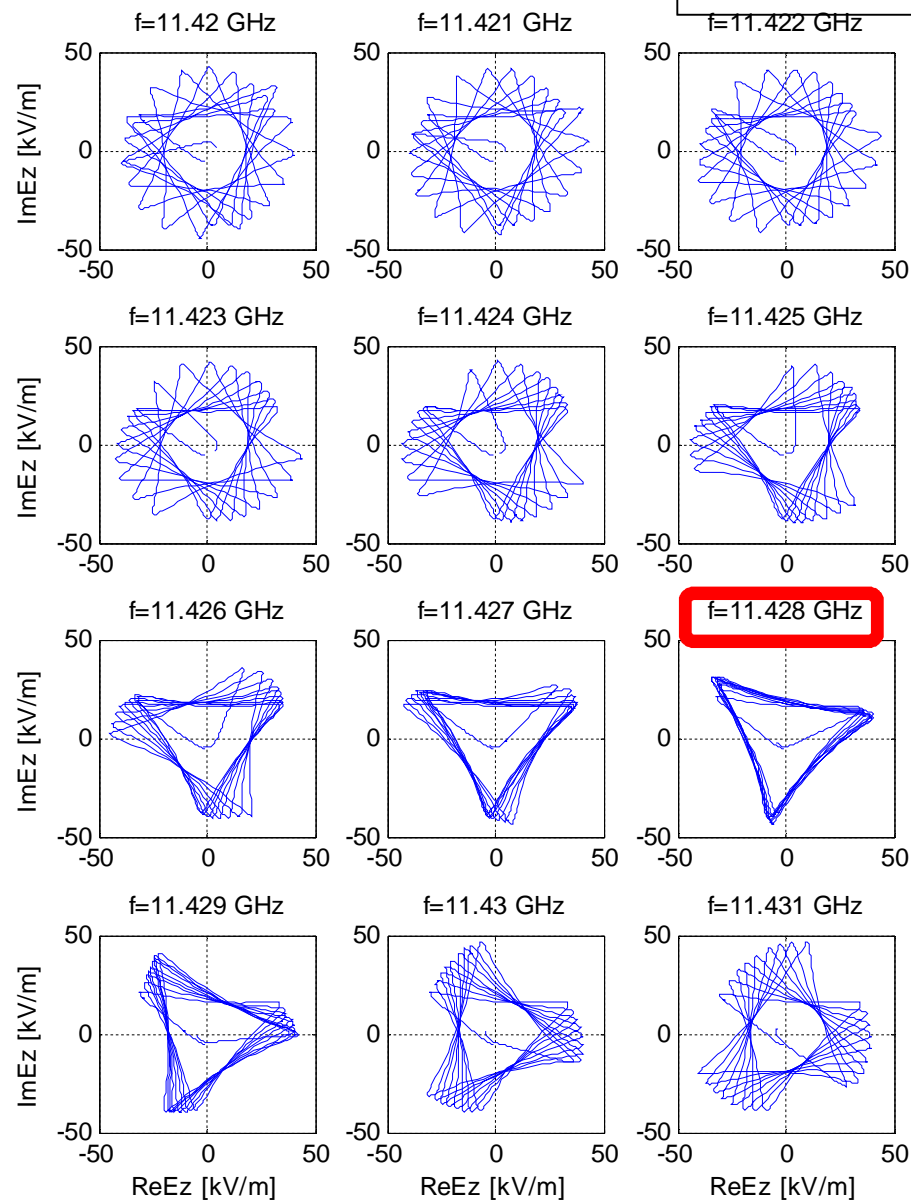
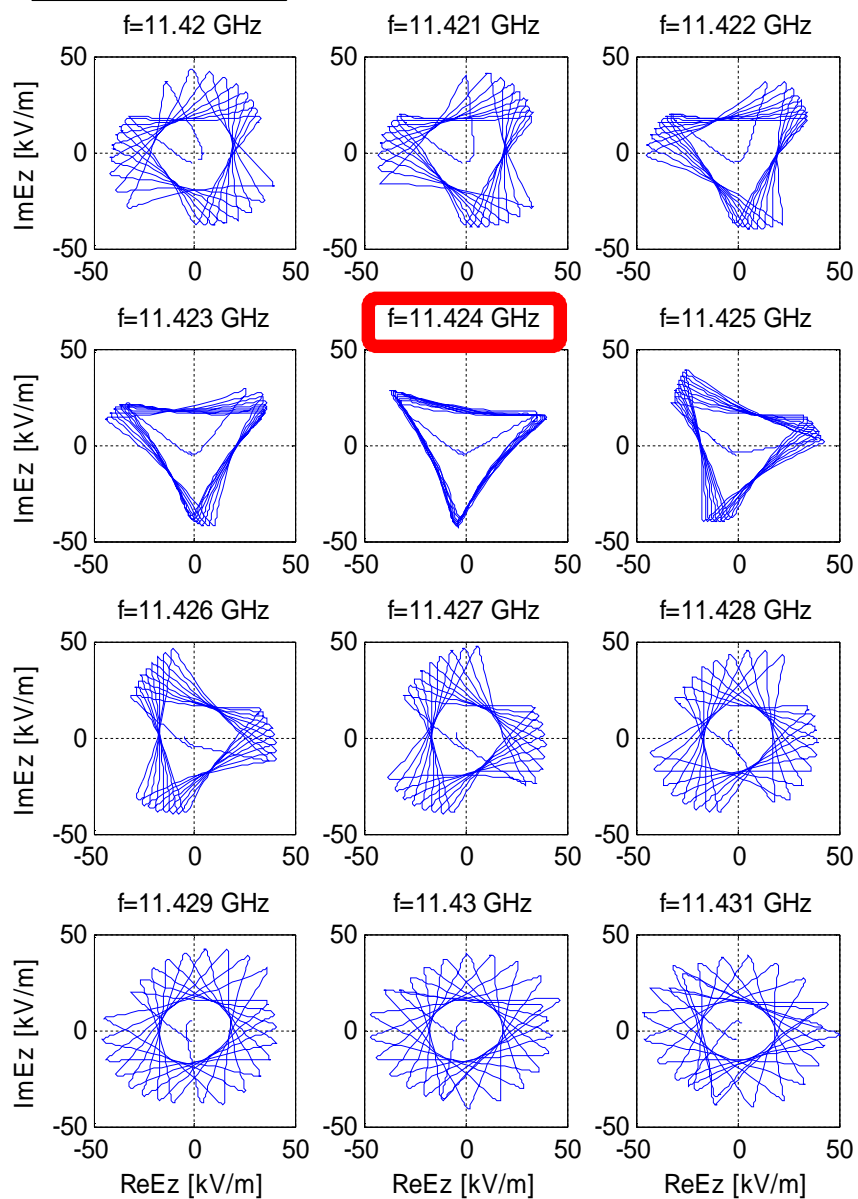
Group delay and Q-factor



RF phase advance per cell

HFSS v10.1

HFSS v11.1



Summary on HFSS

- It seems that there is a bug in HFSS v11.
- The results of the simulations using HFSS v11 are shifted up in frequency by 4 MHz with respect to the results of the simulations using HFSS v10 or S3P
- Use HFSS-S-parameter solver VERSION 10 or S3P